

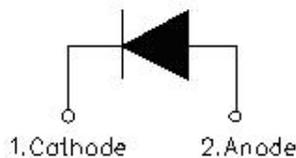
## SDUR60T60W ULTRAFAST RECTIFIER



### Applications:

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### Circuit Diagram



### Features:

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Plastic Material has UL Flammability Classification 94V-0
- This is a Pb – free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	-	600	V
Average Rectified Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_c=70^\circ\text{C}$ , rectangular wave form	60	A
Peak One Cycle Non-Repetitive Surge Current	$I_{FSM}$	8.3ms, Half Sine pulse	350	A

### Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 30A, Pulse, $T_J = 25^\circ\text{C}$ @ 60A, Pulse, $T_J = 25^\circ\text{C}$	1.62 1.92	- 2.2	V
Reverse Current*	$I_{R1}$	@ $V_R = \text{rated } V_R, T_J = 25^\circ\text{C}$	0.1	50	$\mu\text{A}$
	$I_{R2}$	@ $V_R = \text{rated } V_R, T_J = 125^\circ\text{C}$	0.4	10	mA
Reverse Recovery Time	$t_{rr1}$	$I_F = 500\text{mA}, I_R = 1\text{A}, \text{ and } I_{rm} = 250\text{mA}$	30	35	ns
Reverse Recovery Time	$t_{rr2}$	$I_F = 1\text{A}; -di/dt = 200\text{A}/\mu\text{s}; V_R = 30\text{V}, T_C = 25^\circ\text{C}$	35	-	nS
Recovered Charge	$Q_{rr}$	$I_F = 1\text{A}; -di/dt = 200\text{A}/\mu\text{s}; V_R = 30\text{V}, T_C = 25^\circ\text{C}$	43	-	nC

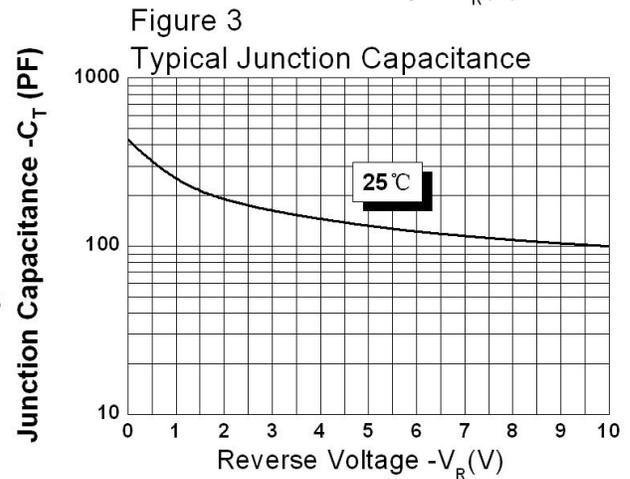
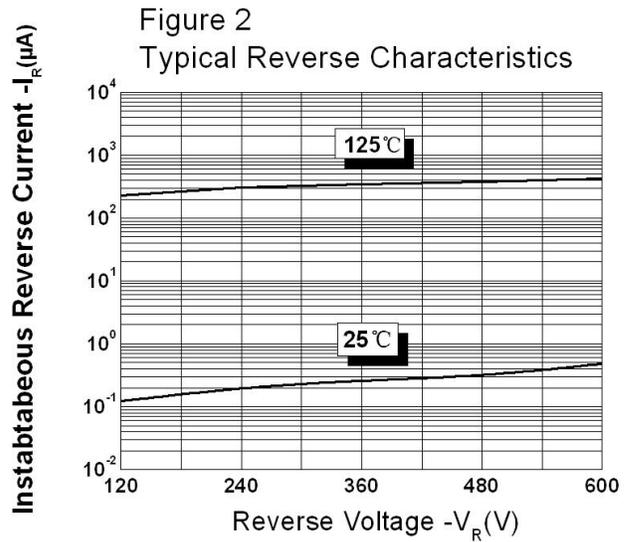
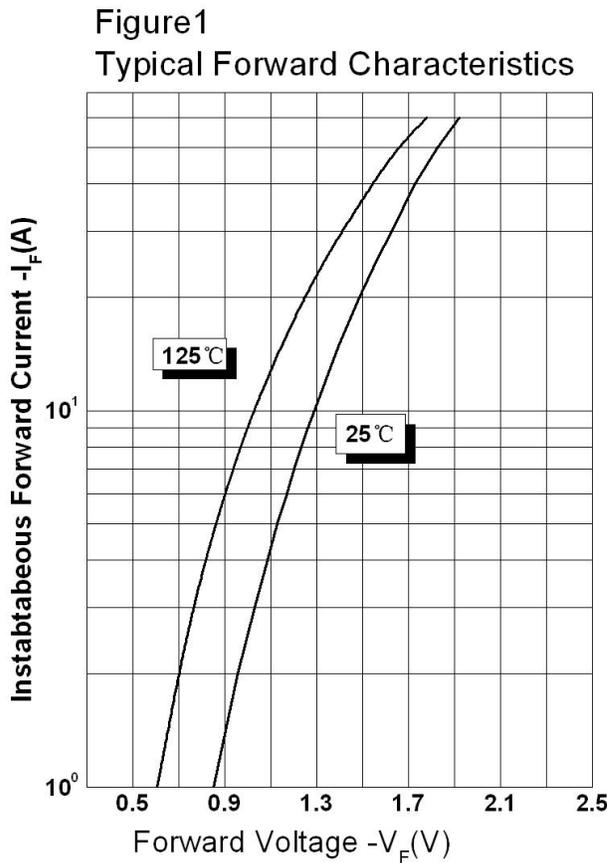
\* Pulse width < 300  $\mu\text{s}$ , duty cycle < 2%

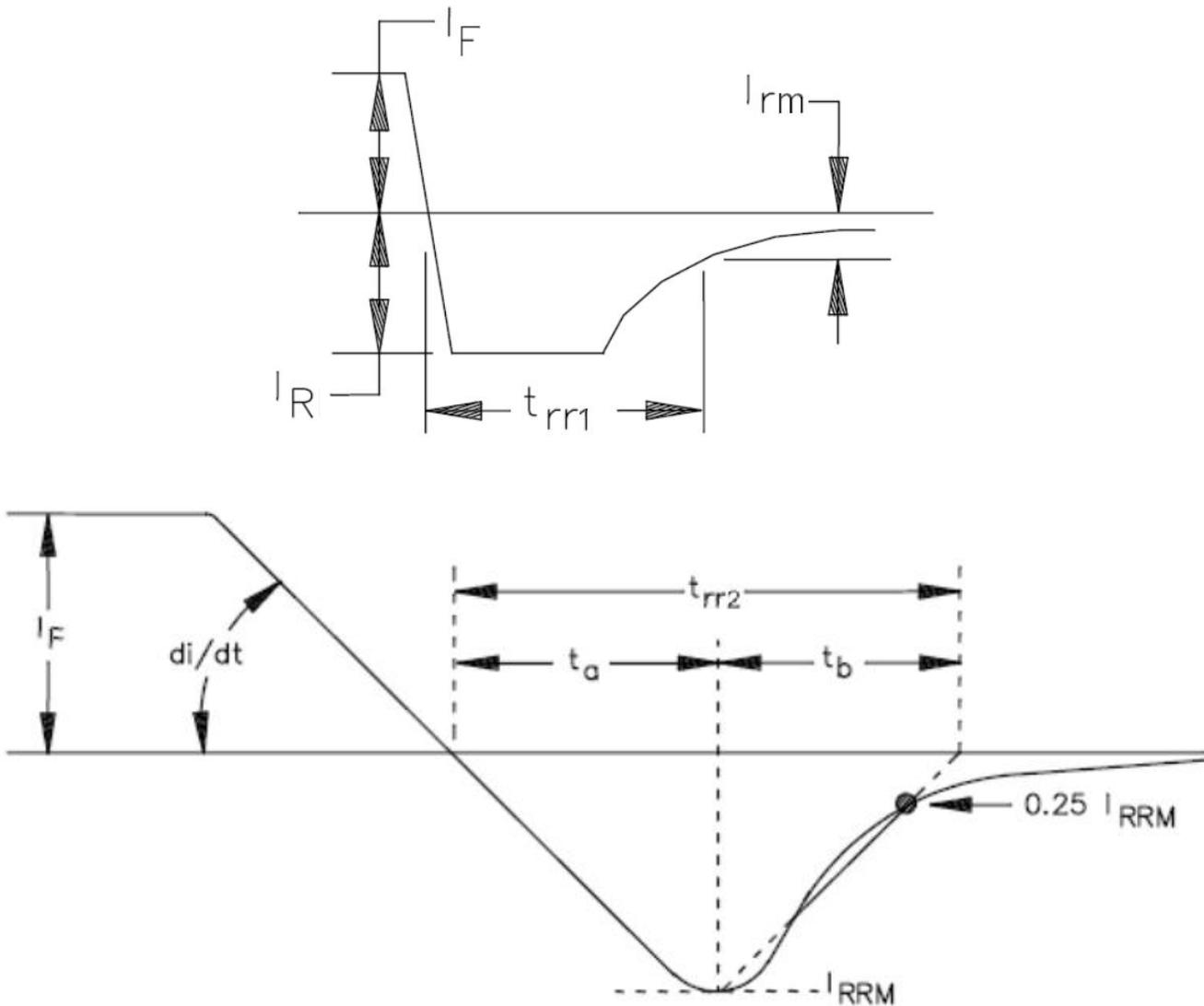
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**Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	$T_J$	-	-55 to +175	°C
Storage Temperature	$T_{stg}$	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	0.34	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AC			

**Ratings and Characteristics Curves**

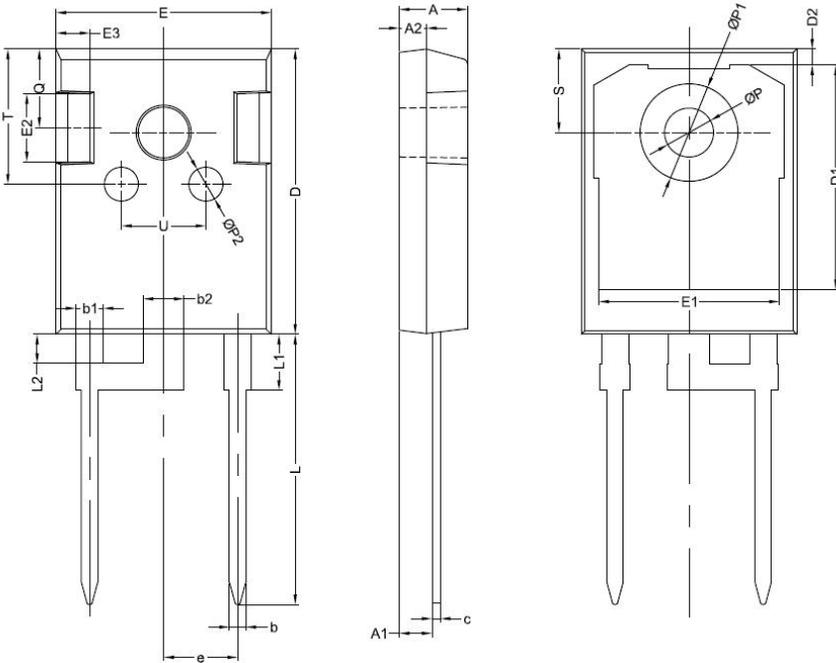




Note: 1.  $t_{rr1}$  MIL-STD-750 Test Method 4031, condition "B".  
2.  $t_{rr2}$  MIL-STD-750 Test Method 4031, condition "D".

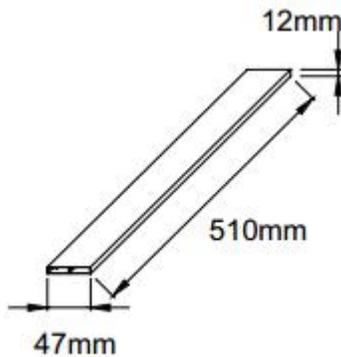
**Figure 4 - Reverse Recovery Waveform**

**Mechanical Dimensions TO-247AC**



SYMBOL	Millimeters		
	MIN.	TYP.	MAX.
A	4.80	5.00	5.20
A1	2.20	2.41	2.61
A2	1.90	2.00	2.10
b	1.00	1.20	1.40
b1	1.80	2.00	2.20
b2	2.80	3.00	3.20
c	0.50	0.60	0.75
D	20.30	21.00	21.20
D1		16.55	
D2		1.20	
E	15.45	15.8	16.0
E1		13.30	
E2		5.00	
E3		2.50	
e		5.44	
L	19.42	19.92	20.42
L1		4.13	
L2		2.15	
P	3.50	3.60	3.70
P1	7.1	-	7.40
P2		2.50	
Q		5.80	
S	6.05	6.15	6.25
T		10.00	
U		6.20	

**Tube Specification**



**Marking Diagram**



Where XXXXX is YYWWL

- SDUR = Device Type
- 60 = Forward Current (60A)
- T = T
- 60 = Reverse Voltage (600V)
- W = Configuration
- SSG = SSG
- YY = Year
- WW = Week
- L = Lot Number

**Cautions:** Molding resin  
Epoxy resin UL:94V-0

**Ordering Information**

Device	Package	Shipping
SDUR60T60W	TO-247AC(Pb-Free)	25pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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